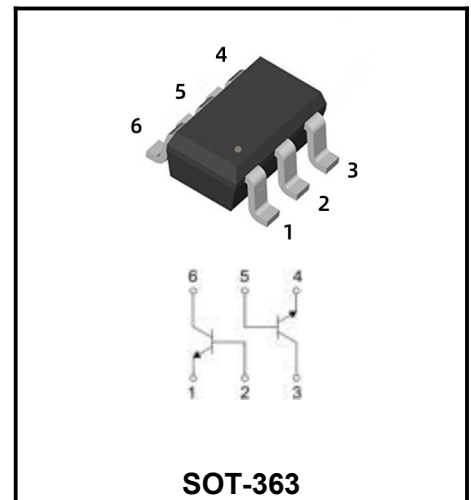


Plastic-Encapsulate Transistors DUAL TRANSISTOR (NPN+NPN)

APPLICATION

This device is designed for general purpose amplifier applications

Marking Code	
BC847ADW	1Et
BC847BDW	1Ft
BC847CDW	1Gt



MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current-Continuous	I _c	100	mA
Power Dissipation	P _D	200	mW
Thermal Resistance. Junction to Ambient	R _{θJA}	625	°C/W
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _c =10μA, I _E =0	50			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _c =1mA, I _B =0	45			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _e =10μA, I _c =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =30V, I _E =0			15	nA
Emitter cut-off current	I _{EBO}	V _{EB} =4V, I _C =0			15	
DC current gain*	h _{FE}	V _{CE} =5V, I _C =2mA	A	110	220	
			B	200	450	
			C	420	800	
Collector-emitter saturation voltage	V _{CE(sat)(1)}	I _C =10mA, I _B =0.5mA			0.25	V
	V _{CE(sat)(2)}	I _C =100mA, I _B =5mA			0.65	V
Base-emitter voltage	V _{BE(1)}	V _{CE} =5V, I _C =2mA	0.58		0.7	V
	V _{BE(2)}	V _{CE} =5V, I _C =10mA			0.77	V
Transition frequency	f _T	V _{CE} =5V, I _C =20mA, f=100MHz		200		MHz
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz		2		pF

*pulse test: Pulse Width ≤300μs, Duty Cycle ≤ 2.0%.

Ordering information

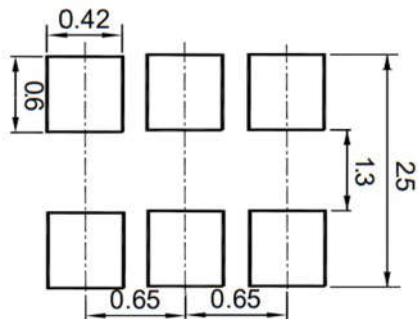
Package	Packing Description	Packing Quantity
SOT-363	Tape/Reel, 7" reel	3000PCS/Reel 120000PCS/Carton

Package Dimensions

SOT-363

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	0.8	1.1	32	43
A1	-	0.1	-	3.94
bp	0.20	0.30	7.87	11.81
c	0.10	0.25	3.94	9.84
D	1.8	2.2	70.87	86.61
E	1.15	1.35	45.28	53.15
e	1.3		51.18	
e1	0.65		25.6	
HE	2.0	2.2	78.74	86.6
Lp	0.15	0.45	5.90	17.71
Q	0.15	0.25	5.90	9.84
v	0.2		7.78	
w	0.2		7.78	
y	0.1		3.94	

The recommended mounting pad size



Disclaimer

The information presented in this document is for reference only. GuangDong Youfeng Microelectronics Co.,Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise. The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices),YFW or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale. This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <https://www.yfwdiode.com>, or consult YFW sales office for further assistance.